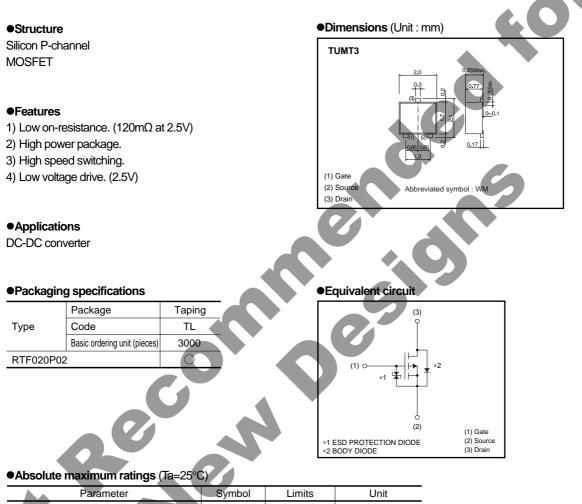
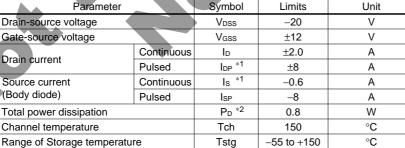
# 2.5V Drive Pch MOSFET

# **RTF020P02**





\*1 Pw≤10μs, Duty cycle≤1% \*2 Mounted on a ceramic board

#### Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a) *	156	°C / W
* Mounted on a ceramic board.			



### Transistors

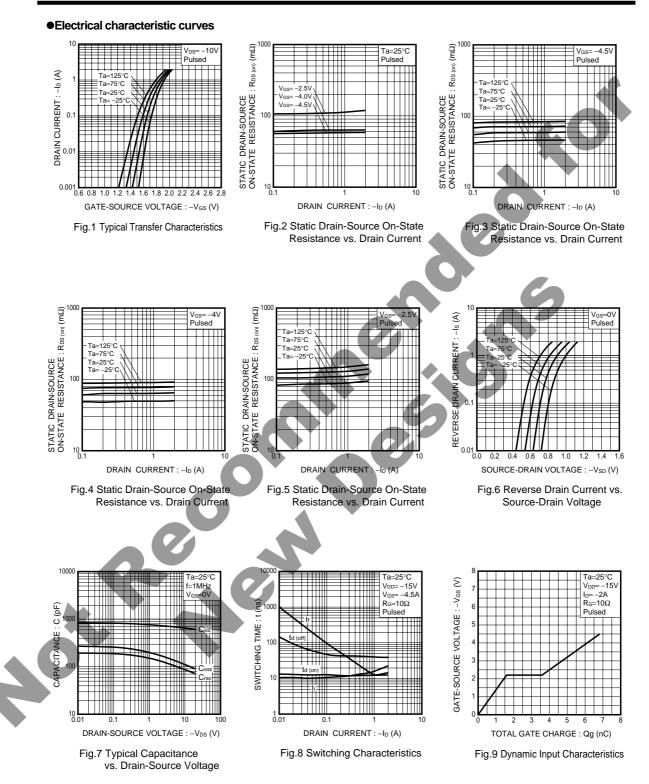
#### Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Gate-source leakage	lgss	-	-	±10	μA	Vgs=±12V, Vds=0V	
Drain-source breakdown voltage	V(BR) DSS	-20	-	-	V	I <sub>D</sub> = -1mA, V <sub>GS</sub> =0V	
Zero gate voltage drain current	IDSS	-	-	-1	μA	V <sub>DS</sub> = -20V, V <sub>GS</sub> =0V	
Gate threshold voltage	VGS (th)	-0.7	-	-2.0	V	$V_{DS} = -10V, I_{D} = -1mA$	
		-	60	85	mΩ	I <sub>D</sub> = -2A, V <sub>GS</sub> = -4.5V	40
Static drain-source on-state resistance	RDS (on)	-	65	90	mΩ	$I_D = -2A$ , $V_{GS} = -4V$	
resistance		-	120	165	mΩ	I <sub>D</sub> = -1A, V <sub>GS</sub> = -2.5V	
Forward transfer admittance	Y <sub>fs</sub> *	2.0	-	-	S	V <sub>DS</sub> = -10V, I <sub>D</sub> = -1A	
Input capacitance	Ciss	-	640	-	pF	V <sub>DS</sub> = -10V	
Output capacitance	Coss	-	110	-	pF	Vgs=0V	
Reverse transfer capacitance	Crss	-	85	-	pF	f=1MHz	
Turn-on delay time	t <sub>d (on)</sub> *	_	12	-	ns	ID= -1A	
Rise time	tr *	-	15	-	ns	VDD≒ -15V	
Turn-off delay time	td (off) *	-	40	-	ns	V <sub>GS</sub> = –4.5V R∟=15Ω	
Fall time	t <sub>f</sub> *	-	12	-	ns	R <sub>G</sub> =10Ω	
Total gate charge	Qg *	-	7.0	-	nC	V <sub>DD</sub> ≒-15V R <b>∟=7</b> .5Ω	
Gate-source charge	Q <sub>gs</sub> *	-	1.6	-	nC	V <sub>GS</sub> =-4.5V R <sub>G</sub> =10Ω	
Gate-drain charge	Q <sub>gd</sub> *	-	2.0	-	nC	ID=-2A	
⊧Pulsed							

Gate-drain charge	Q <sub>gd</sub> *	_	2.0	_	nC	ID=-2A
*Pulsed	. <u> </u>					
Body diode characteristic						
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsd	-	-	-1.2	V	Is= -0.6A, V <sub>GS</sub> =0V
	·					

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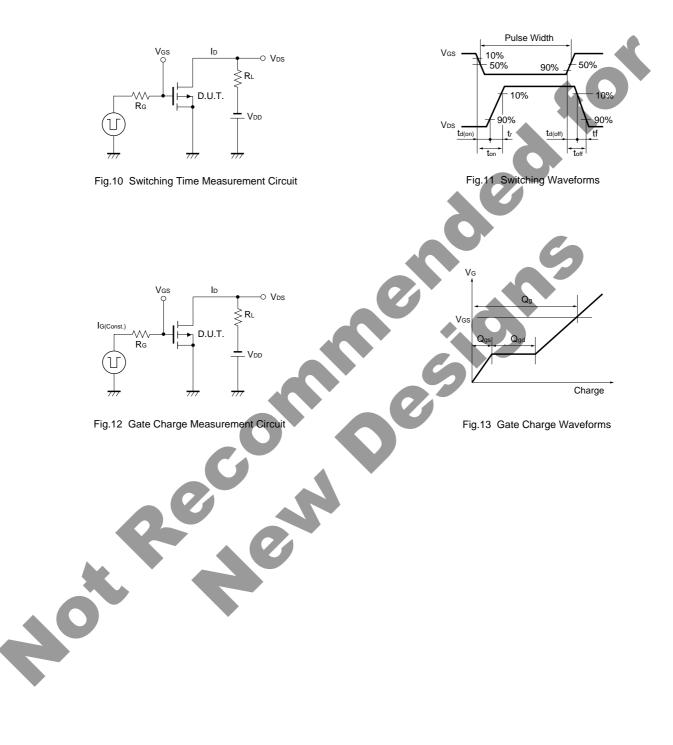
#### Transistors



Rev.C

### Transistors

#### Measurement circuits



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